## PROBLEM SET \#10

Issued: Friday, November 2, 2018
Due: Friday, November 16, 2018, at 12:00 noon via Gradescope.

1. Sedra \& Smith, Problem 8.98
2. For the amplifier in Figure $\operatorname{PS} 10.1$, assume that $Q_{1}$ and $Q_{2}$ have the properties listed in Table PS10.1. First, find values for each of the BJT internal capacitances $C_{\mu}, C_{\pi}$. Then find the voltage gain $A_{v}\left(\frac{v_{\text {out }}}{v_{s}}\right)$, input and output resistances $R_{\text {in }} \& R_{\text {out }}$, and upper and lower corner frequencies $f_{L} \& f_{H}$.


Figure PS10.1

| PARAMETER | VALUE | UNIT |
| :---: | :---: | :---: |
| $\beta$ | 100 | $A / A$ |
| $V_{A}$ | 70 | $V$ |
| $V_{b i, e}$ | 0.9 | $V$ |
| $V_{b i, c}$ | 0.5 | $V$ |
| $L_{o v}$ | 0.05 | $\mu m$ |
| $C_{j c, 0}$ | 4 | $p F$ |
| $C_{j e, 0}$ | 8 | $p F$ |
| $\tau_{F}$ | 350 | $p s$ |
|  | Table PS10.1 |  |

3. For the amplifier in Figure PS10.2, assume that $M_{1}$ and $M_{2}$ have the parameters listed in Table PS10.2. Find $A_{v}\left(\frac{v_{\text {out }}}{v_{s}}\right), R_{\text {in }}, R_{\text {out }}, f_{L}$, and $f_{H}$.


Figure PS10.2

| PARAMETER | VALUE | UNIT |
| :---: | :---: | :---: |
| $W$ | 200 | $\mu m$ |
| $L$ | 1.2 | $\mu m$ |
| $\mu_{n}$ | 450 | $\mathrm{~cm}^{2} /(\mathrm{V} \cdot \mathrm{s})$ |
| $\mu_{p}$ | 250 | $\mathrm{~cm}^{2} /(\mathrm{V} \cdot \mathrm{s})$ |
| $C_{o x}{ }^{\prime \prime}$ | 0.5 | $\mathrm{fF} / \mathrm{\mu m}^{2}$ |
| $V_{t n}$ | -2 | $V$ |
| $V_{t p}$ | 4 | $V$ |
| $L_{o v}$ | 0.1 | $\mu m$ |
| $C_{d b 0}$ | 20 | $f F$ |
| $C_{s b 0}$ | 20 | $f F$ |
| $V_{0}$ | 0.7 | $V$ |
| $\lambda$ | 0.02 | $V^{-1}$ |

Table PS10.2
4. For the amplifier in Figure PS10.3, assume that $M_{1}$ has the properties listed in Table PS10.2, and that $Q_{1}$ has the properties listed in Table PS10.1. Find $A_{v}\left(\frac{v_{\text {out }}}{v_{s}}\right), R_{\text {in }}, R_{\text {out }}, f_{L}$, and $f_{H}$.


Figure PS10.3
5. For the amplifier in Figure PS10.4, assume that $Q_{1}$ and $Q_{2}$ have the properties listed in Table PS10.1. Find $A_{v}\left(\frac{v_{\text {out }}}{v_{s}}\right), R_{\text {in }}, R_{\text {out }}, f_{L}$, and $f_{H}$.


Figure PS10.4
6. Find the Q-points of the transistors in Figure PS10.2 if $C_{2}$ is replaced with a short circuit and the $1 M \Omega$ resistor is removed from the circuit.
7. For the circuit shown in Figure PS10.5, $X_{1}$ is an ideal OpAmp and assume $M_{1}$ and $M_{2}$ have the properties listed in Table PS10.2. Assume $Q_{2}$ has the properties listed in Table PS 10.1. $Q_{1}$ is a parallel combination of four $n p n$ transistors having the properties listed in Table PS 10.1. Find the expression of $\mathbf{V}_{\mathbf{P}}$ and $\mathbf{V}_{\mathbf{c}}$. [Hint: You may assume both $Q_{1}$ and $Q_{2}$ are biased in forward active region. In addition, this is a case where you cannot just assume the diodes' turnon voltage is $V_{B E(o n)}$. You will need to be more accurate.]


Figure PS10.5
8. For the circuit shown in Figure PS10.6. $Q_{1}, Q_{2}$ and $Q_{3}$ have the same properties, and $Q_{4}$ and $Q_{5}$ have the same properties. $V_{B E, o n, Q 1}=0.7 \mathrm{~V}, V_{B E, o n, Q 4}=0.65 \mathrm{~V}$. Solve of $V_{R E F}$. Neglect early effect.


Figure PS10.6

